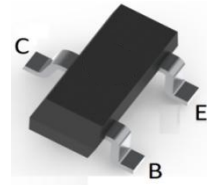
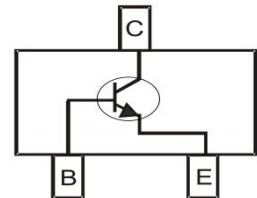


BIPOLAR TRANSISTOR (NPN)
FEATURES

- Complementary to BC858
- Ideally suited for automatic insertion
- For switching and AF amplifier applications
- Surface Mount device


SOT-23

MECHANICAL DATA

- Case: SOT-23
- Case Material: Molded Plastic. UL flammability
- Classification Rating: 94V-0
- Weight: 0.008 grams (approximate)

MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	V _{CB0}	30	V
Collector-Emitter Voltage	V _{CEO}	30	V
Emitter-Base Voltage	V _{EBO}	6	V
Collector Current	I _C	100	mA
Collector Power Dissipation	P _C	200	mW
Thermal Resistance From Junction To Ambient	R _{θJA}	625	°C/W
Junction Temperature	T _J	150	°C
Storage Temperature	T _{STG}	-55 ~+150	°C

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Collector-base breakdown voltage	V _{(BR)CBO}	30			V	I _C =10uA, I _E =0
Collector-emitter breakdown voltage	V _{(BR)CEO}	30			V	I _C =10mA, I _B =0
Emitter-base breakdown voltage	V _{(BR)EBO}	6			V	I _E =10uA, I _C =0
Collector cut-off current	I _{CBO}			0.1	uA	V _{CB} =30V, I _E =0
Emitter cut-off current	I _{EBO}			0.1	uA	V _{EB} =5V, I _C =0
DC current gain	h _{FE1}	110		800		V _{CE} =5V, I _C =2mA
Collector-emitter saturation voltage	V _{CE(sat)}			0.5	V	I _C =100mA, I _B =5mA
Base-emitter saturation voltage	V _{BE(sat)}			1.1	V	I _C =100mA, I _B =5mA
Transition frequency	f _T	100			MHz	V _{CE} =5V, I _C =10mA, f=100MHz
Collector output capacitance	C _{ob}			4.5	pF	V _{CE} =10V, I _E =0, f=1MHz

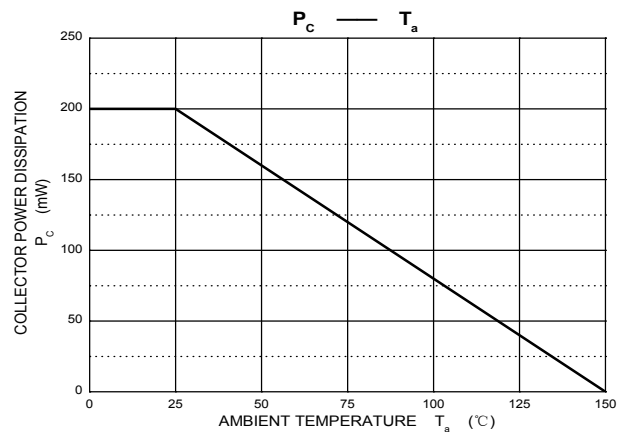
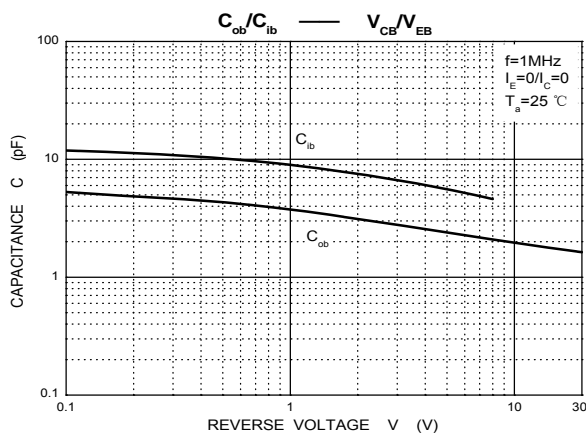
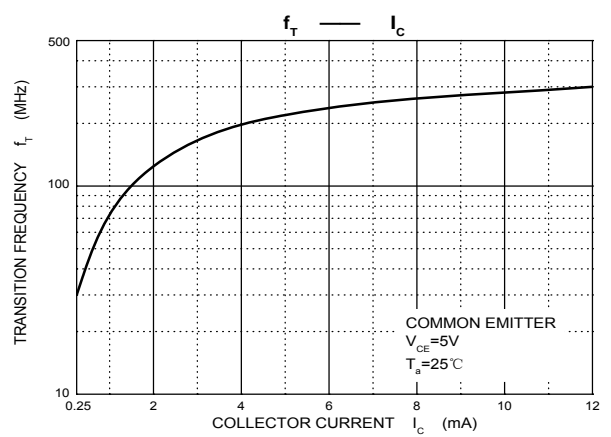
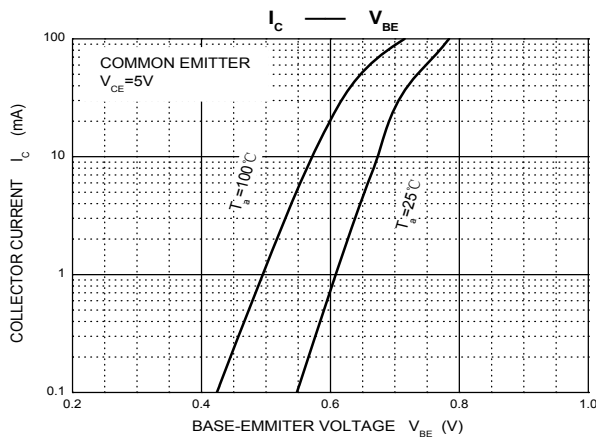
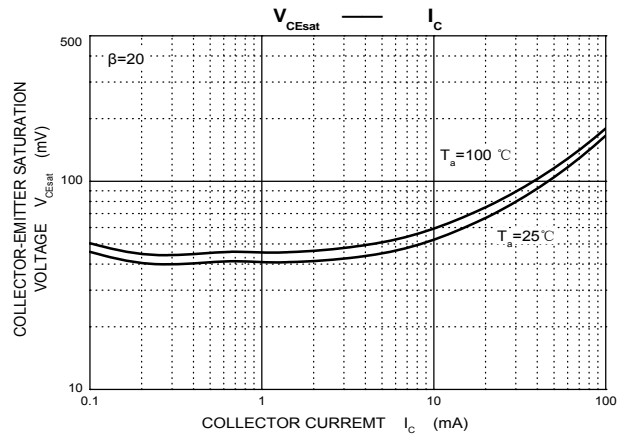
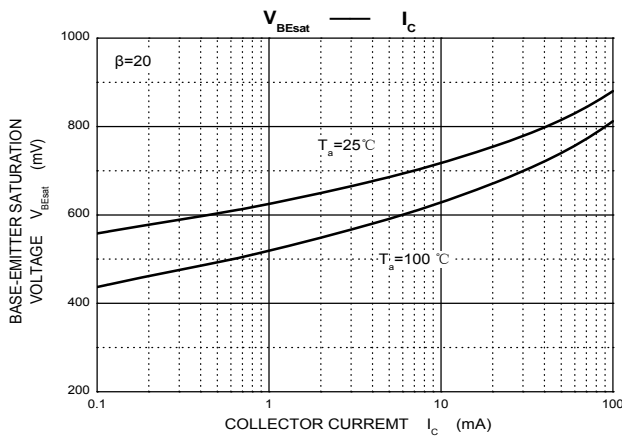
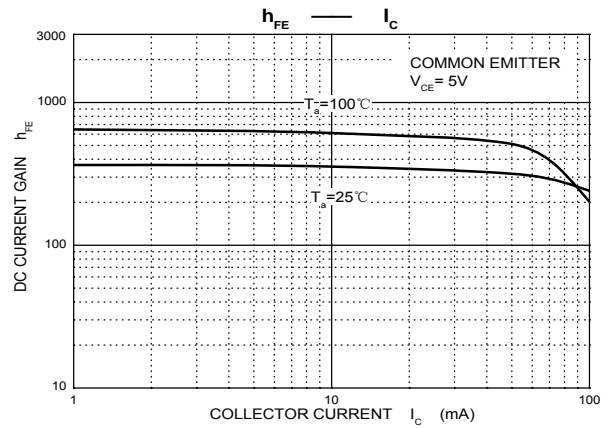
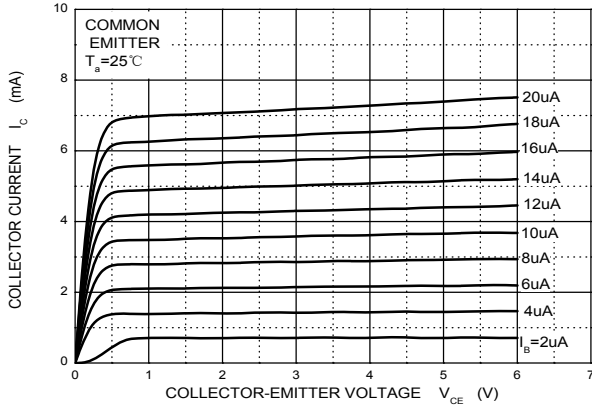
CLASSIFICATION OF h_{FE}

Rank	BC848A	BC848B	BC848C
Range	110-220	200-450	420-800
Marking	1J	1K	1L

BIPOLAR TRANSISTOR (NPN)

Typical Characteristics

Static Characteristic



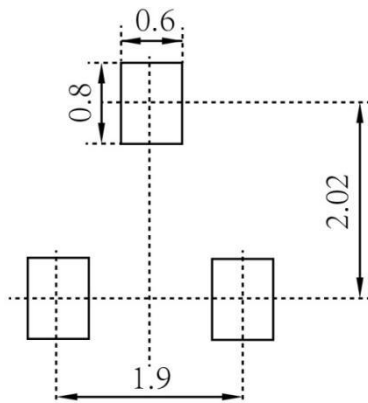
BIPOLAR TRANSISTOR (NPN)

SOT-23 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

SOT-23 Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters
2. General tolerance: $\pm 0.05\text{mm}$
3. The pad layout is for reference purposes only

BIPOLAR TRANSISTOR (NPN)

SOT-23 Tape and Reel

SOT-23 Embossed Carrier Tape

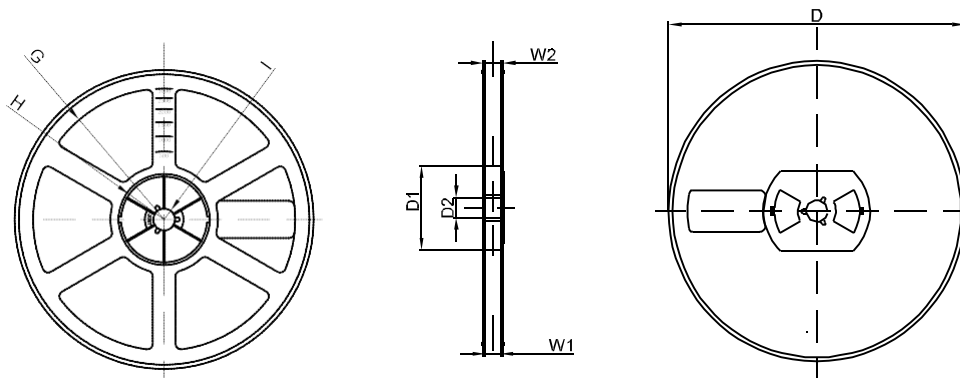


DIMENSIONS ARE IN MILLIMETER										
TYPE	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00
TOLERANCE	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1	±0.1

SOT-23 Tape Leader and Trailer



SOT-23 Reel



DIMENSIONS ARE IN MILLIMETER								
REEL OPTION	D	D1	D2	G	H	I	W1	W2
7" DIA	Ø178	54.40	13.00	R78	R25.60	R6.50	9.50	12.30
TOLERANCE	±2	±1	±1	±1	±1	±1	±1	±1

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